# BAS16M3T5G

# **Switching Diode**

### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	75	Vdc
Peak Forward Current	١ <sub>F</sub>	200	mAdc
Peak Forward Surge Current	I <sub>FM(surge)</sub>	500	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Total Device Dissipation, FR-4 Board (Note 1) T <sub>A</sub> = 25°C	P <sub>D</sub>	260	mW
Derated above 25°C		2.0	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ hetaJA}$	490	°C/W
Total Device Dissipation, FR–4 Board (Note 2) T <sub>A</sub> = 25°C Derated above 25°C	P <sub>D</sub>	580 4.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	215	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

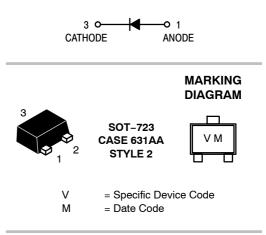
1. FR-4 @ Minimum Pad

2. FR-4 @  $1.0 \times 1.0$  Inch Pad



## **ON Semiconductor®**

http://onsemi.com



### **ORDERING INFORMATION**

	Device	Package	Shipping <sup>†</sup>
BA	AS16M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

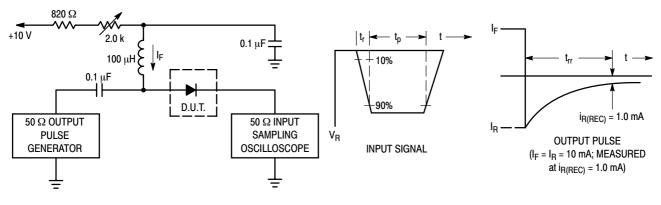
+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current ( $V_R = 75 \text{ Vdc}$ ) ( $V_R = 75 \text{ Vdc}$ , $T_J = 150^{\circ}\text{C}$ ) ( $V_R = 25 \text{ Vdc}$ , $T_J = 150^{\circ}\text{C}$ )	I <sub>R</sub>	- - -	1.0 50 30	μAdc
Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μAdc)	V <sub>(BR)</sub>	75	-	Vdc
Forward Voltage $(I_F = 1.0 \text{ mAdc})$ $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 150 \text{ mAdc})$	V <sub>F</sub>		715 855 1000 1250	mV
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	CD	-	2.0	pF
Forward Recovery Voltage (I <sub>F</sub> = 10 mAdc, t <sub>r</sub> = 20 ns)	V <sub>FR</sub>	-	1.75	Vdc
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, R_L = 50 \Omega)$	t <sub>rr</sub>	-	6.0	ns
Stored Charge (I <sub>F</sub> = 10 mAdc to V <sub>R</sub> = 5.0 Vdc, $R_L = 500 \ \Omega$ )	Q <sub>S</sub>	-	45	рС

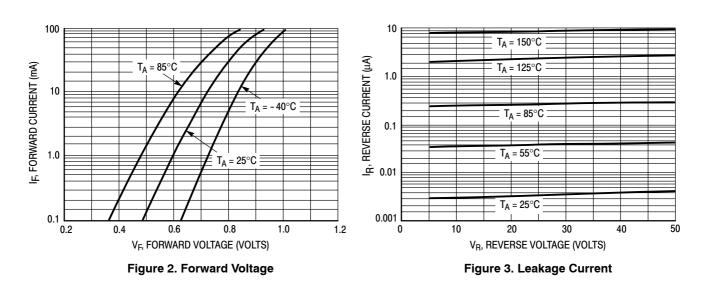
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Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10 mA.

3. t<sub>p</sub> » t<sub>rr</sub>

### Figure 1. Recovery Time Equivalent Test Circuit



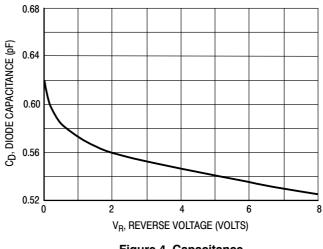
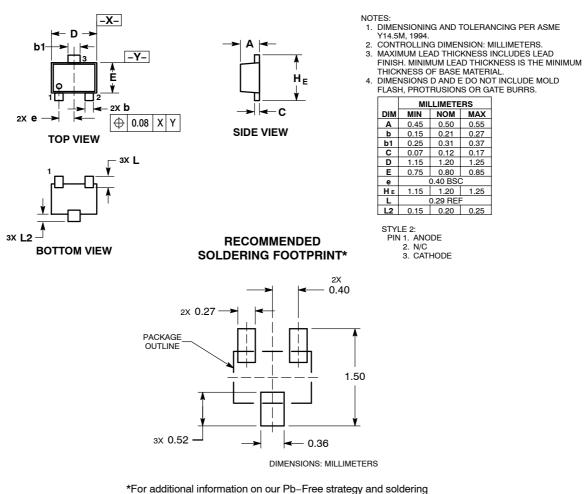


Figure 4. Capacitance

### PACKAGE DIMENSIONS

SOT-723 CASE 631AA ISSUE D



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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